



BIPOLAR ANALOG INTEGRATED CIRCUIT

μ PC8236T6N

SiGe:C LOW NOISE AMPLIFIER FOR GPS

DESCRIPTION

The μ PC8236T6N is a silicon germanium carbon (SiGe:C) monolithic integrated circuit designed as low noise amplifier for GPS. This device exhibits low noise figure and high power gain characteristics, so this IC can improve the sensitivity of GPS receiver. In addition, the μ PC8236T6N which is included output matching circuit contributes to reduce external components and system size.

The package is a 6-pin plastic TSON (Thin Small Out-line Non-leaded) (T6N) suitable for surface mount.

This IC is manufactured using our UHS4 (Ultra High Speed Process) SiGe:C bipolar process.

FEATURES

- Supply voltage : $V_{CC} = 1.6$ to 3.3 V (2.7 V TYP.)
- Low noise : NF = 0.8 dB TYP. @ $V_{CC} = 2.7$ V, $f_{in} = 1$ 575 MHz
: NF = 0.8 dB TYP. @ $V_{CC} = 1.8$ V, $f_{in} = 1$ 575 MHz
- High gain : GP = 19.5 dB TYP. @ $V_{CC} = 2.7$ V, $f_{in} = 1$ 575 MHz
: GP = 19.1 dB TYP. @ $V_{CC} = 1.8$ V, $f_{in} = 1$ 575 MHz
- Low current consumption : $I_{CC} = 6.5$ mA TYP. @ $V_{CC} = 2.7$ V
- Built-in power-saving function : $V_{PSon} = 1.0$ V to V_{CC} , $V_{PSoff} = 0$ to 0.4 V
- High-density surface mounting : 6-pin plastic TSON (T6N) package ($1.5 \times 1.5 \times 0.37$ mm)
- Included output matching circuit
- Included very robust bandgap regulator (Small V_{CC} and T_A dependence)
- Included protection circuits for ESD

APPLICATION

- Low noise amplifier for GPS

ORDERING INFORMATION

Part Number	Order Number	Package	Marking	Supplying Form
μ PC8236T6N-E2	μ PC8236T6N-E2-A	6-pin plastic TSON (T6N) (Pb-Free)	6S	<ul style="list-style-type: none">• 8 mm wide embossed taping• Pin 1, 6 face the perforation side of the tape• Qty 3 kpcs/reel

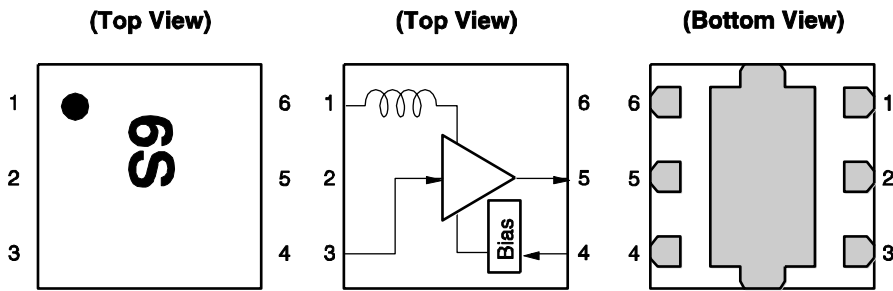
Remark To order evaluation samples, contact your nearby sales office.

Part number for sample order: μ PC8236T6N-A

Caution: Observe precautions when handling because these devices are sensitive to electrostatic discharge

The information in this document is subject to change without notice. Before using this document, please confirm that this is the latest version.

PIN CONNECTIONS AND INTERNAL BLOCK DIAGRAM



Pin No.	Pin Name
1	V _{CC}
2	GND
3	INPUT
4	Power Save
5	OUTPUT
6	V _{CC}

Remark Exposed pad : GND

ABSOLUTE MAXIMUM RATINGS

Parameter	Symbol	Test Conditions	Ratings	Unit
Supply Voltage	V _{CC}	T _A = +25°C	4.0	V
Power-Saving Voltage	V _{PS}	T _A = +25°C	4.0	V
Total Power Dissipation	P _{tot}		150	mW
Operating Ambient Temperature	T _A		-40 to +85	°C
Storage Temperature	T _{stg}		-55 to +150	°C
Input Power	P _{in}		+10	dBm

RECOMMENDED OPERATING RANGE

Parameter	Symbol	MIN.	TYP.	MAX.	Unit
Supply Voltage	V _{CC}	1.6	2.7	3.3	V
Operating Ambient Temperature	T _A	-40	+25	+85	°C
Power Save Turn-on Voltage	V _{PSon}	1.0	-	V _{CC}	V
Power Save Turn-off Voltage	V _{PSoff}	0	-	0.4	V

ELECTRICAL CHARACTERISTICS

(T_A = +25°C, V_{CC} = V_{PS} = 2.7 V, f_{in} = 1 575 MHz, unless otherwise specified)

Parameter	Symbol	Test Conditions	MIN.	TYP.	MAX.	Unit
Circuit Current	I _{CC}	No Signal (V _{PS} = 2.7 V)	5.0	6.5	8.0	mA
		At Power-Saving Mode (V _{PS} = 0 V)	-	-	1	μA
Power Gain	G _P	P _{in} = -35 dBm	17	19.5	22	dB
Noise Figure	NF		-	0.8	1.1	dB
Input Return Loss	RL _{in}		7.5	11	-	dB
Output Return Loss	RL _{out}		11	14	-	dB

STANDARD CHARACTERISTICS FOR REFERENCE 1

($T_A = +25^\circ\text{C}$, $V_{CC} = V_{PS} = 2.7\text{ V}$, $f_{in} = 1\ 575\text{ MHz}$, unless otherwise specified)

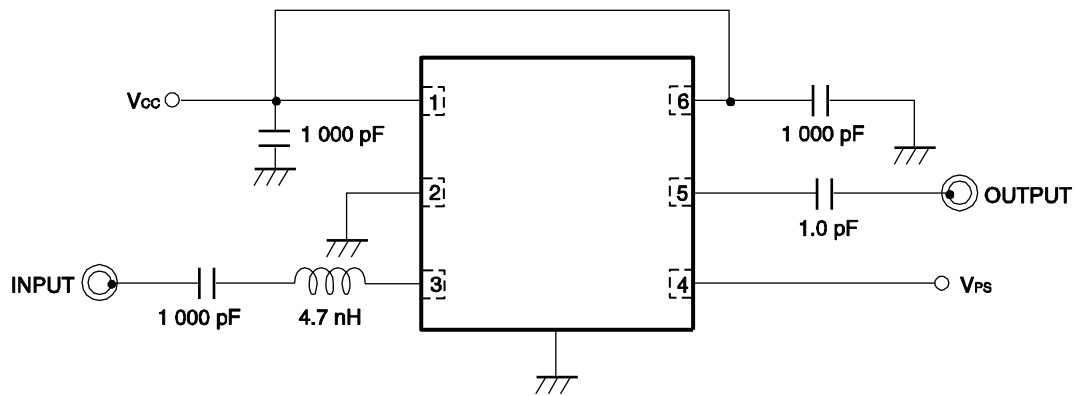
Parameter	Symbol	Test Conditions	Reference	Unit
Input 3rd Order Intercept Point	IIP ₃	$f_{in1} = 1\ 575\text{ MHz}$, $f_{in2} = 1\ 574\text{ MHz}$	-3	dBm
Isolation	ISL		39	dB
Gain 1 dB Compression Input Power	$P_{in(1\text{ dB})}$		-18	dBm

STANDARD CHARACTERISTICS FOR REFERENCE 2

($T_A = +25^\circ\text{C}$, $V_{CC} = V_{PS} = 1.8\text{ V}$, $f_{in} = 1\ 575\text{ MHz}$, unless otherwise specified)

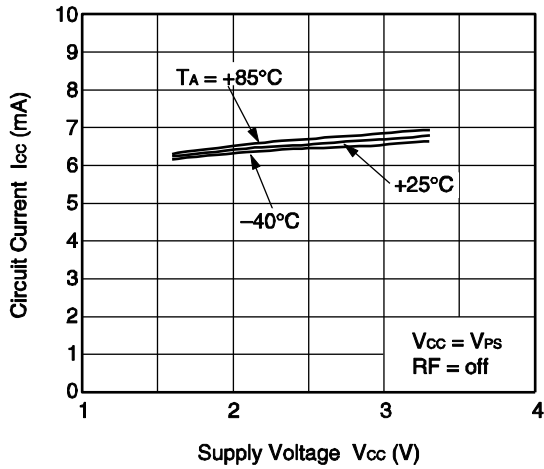
Parameter	Symbol	Test Conditions	Reference	Unit
Circuit Current	I _{CC}	No Signal ($V_{PS} = 1.8\text{ V}$)	6.2	mA
Power Gain	G _P	$P_{in} = -35\text{ dBm}$	19.1	dB
Noise Figure	NF		0.8	dB
Input 3rd Order Intercept Point	IIP ₃	$f_{in1} = 1\ 575\text{ MHz}$, $f_{in2} = 1\ 574\text{ MHz}$	-5	dBm
Input Return Loss	RL _{in}		11	dB
Output Return Loss	RL _{out}		14	dB
Isolation	ISL		39	dB
Gain 1 dB Compression Input Power	$P_{in(1\text{ dB})}$		-19	dBm

TEST CIRCUIT

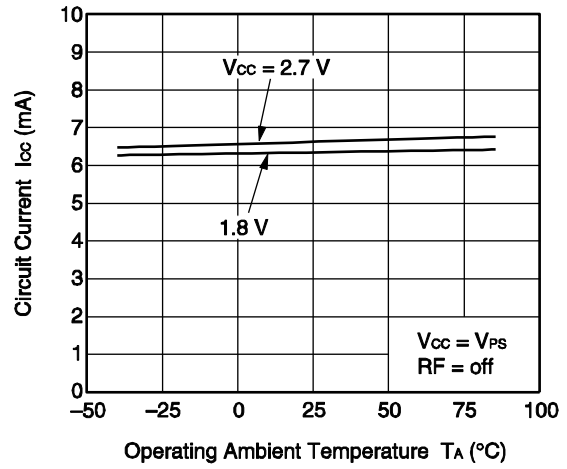


TYPICAL CHARACTERISTICS ($T_A = +25^\circ\text{C}$, unless otherwise specified)

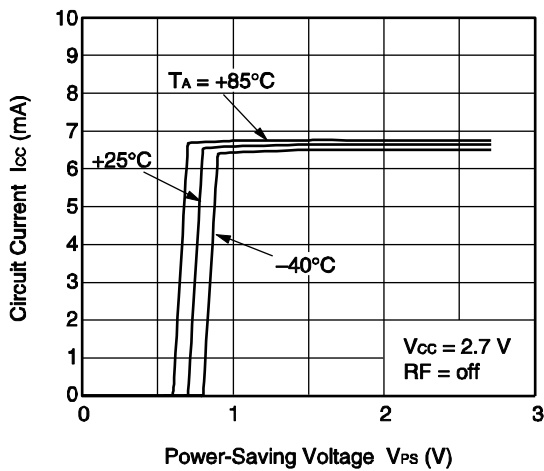
CIRCUIT CURRENT vs. SUPPLY VOLTAGE



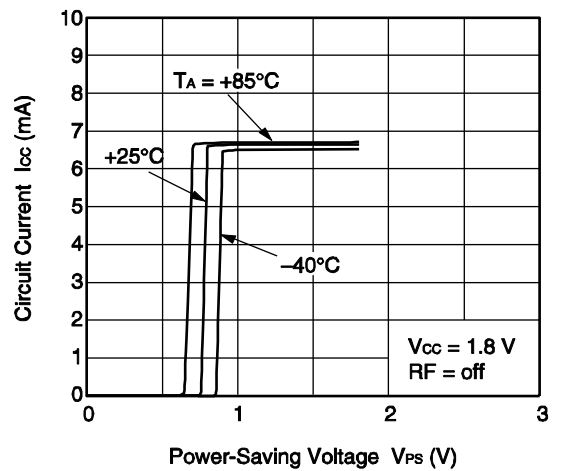
CIRCUIT CURRENT vs. OPERATING AMBIENT TEMPERATURE



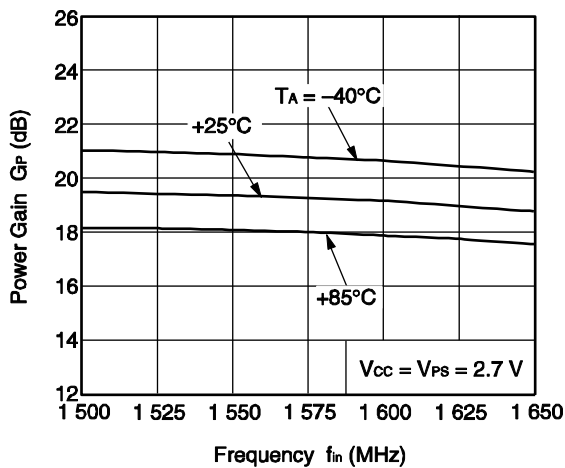
CIRCUIT CURRENT vs. POWER-SAVING VOLTAGE



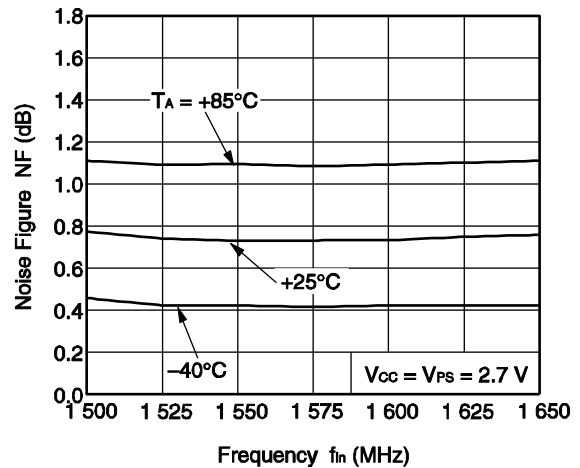
CIRCUIT CURRENT vs. POWER-SAVING VOLTAGE



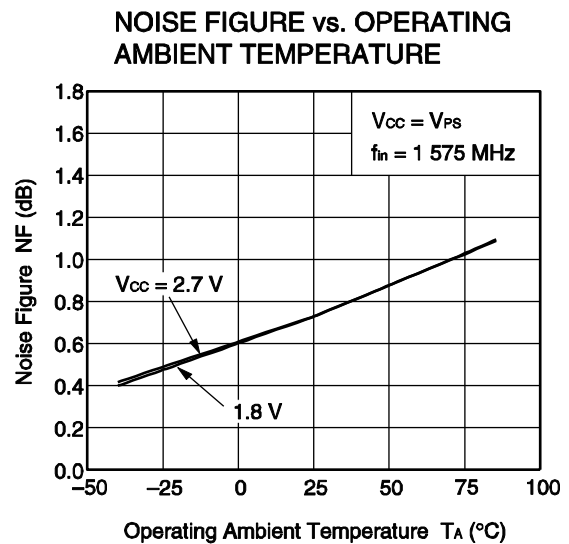
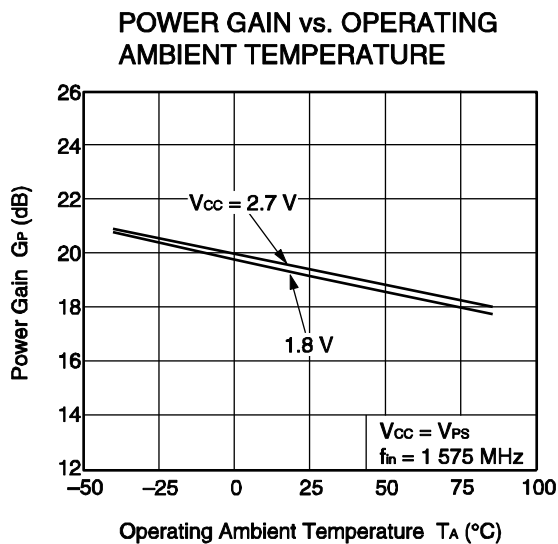
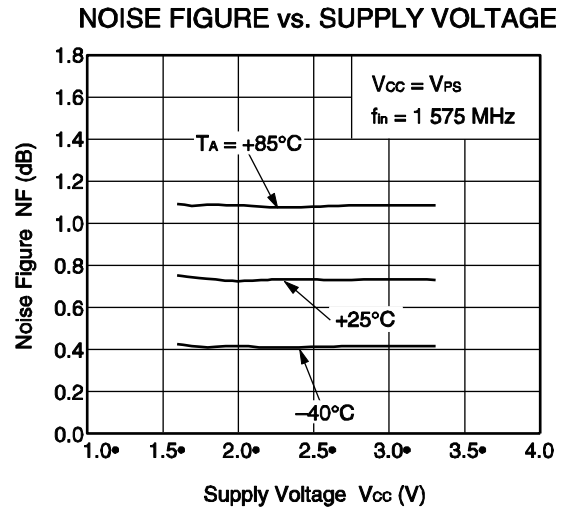
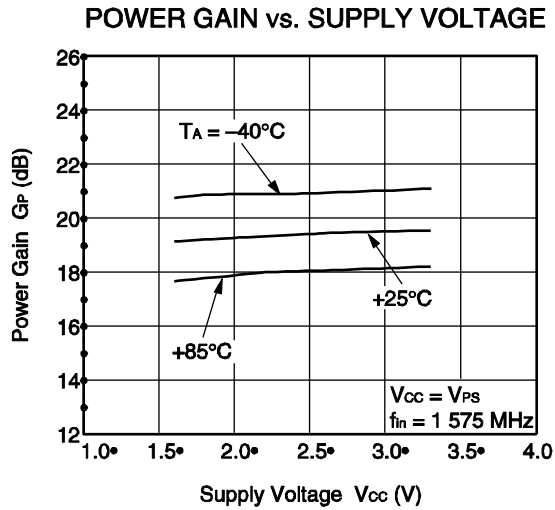
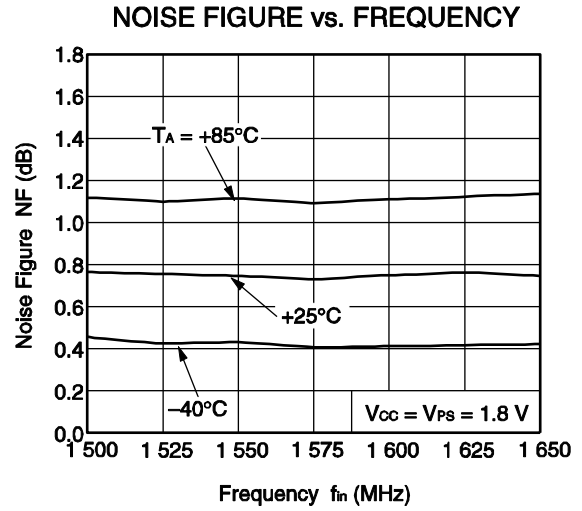
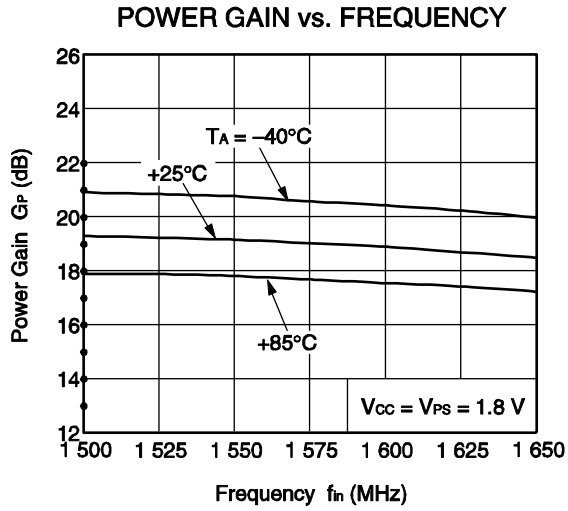
POWER GAIN vs. FREQUENCY



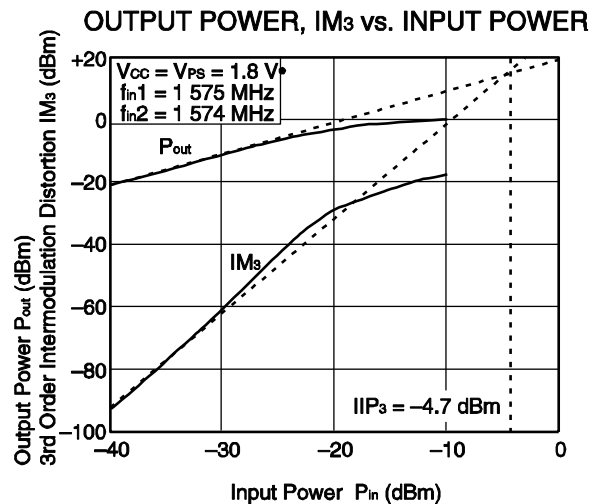
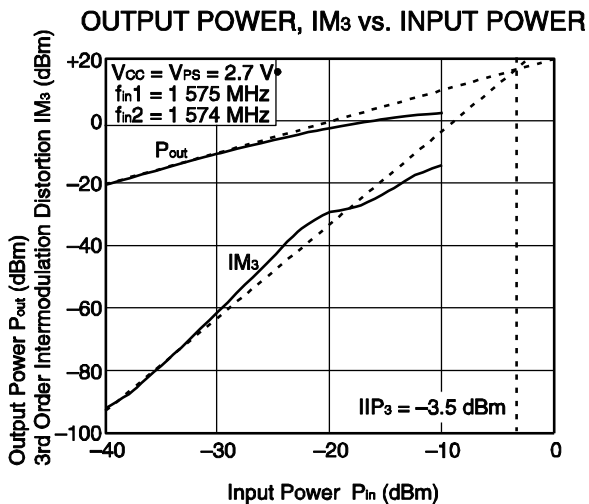
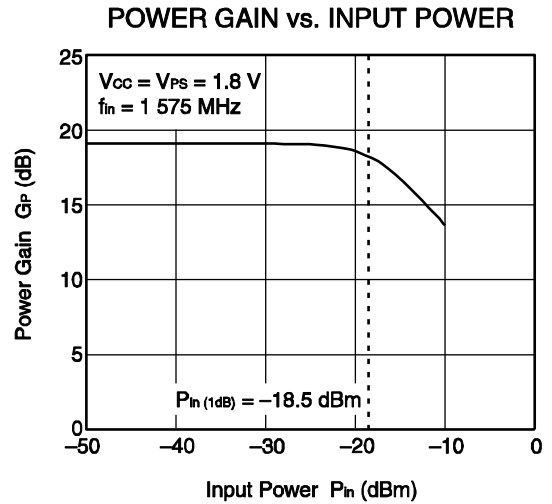
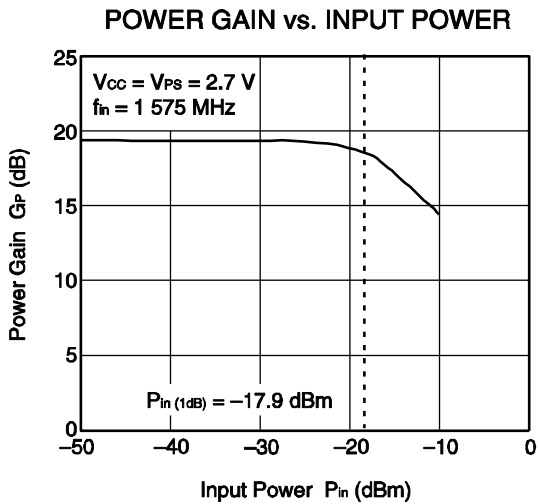
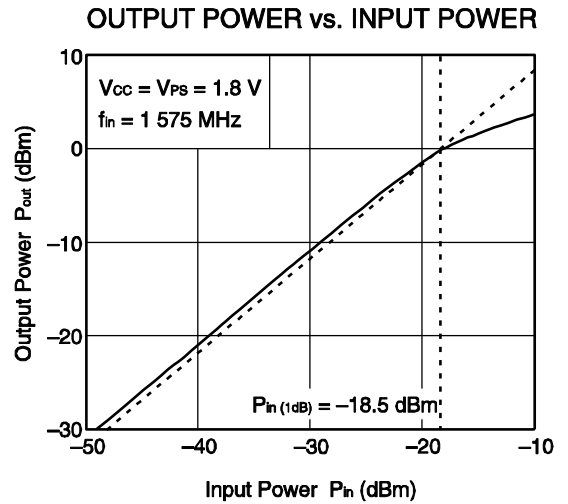
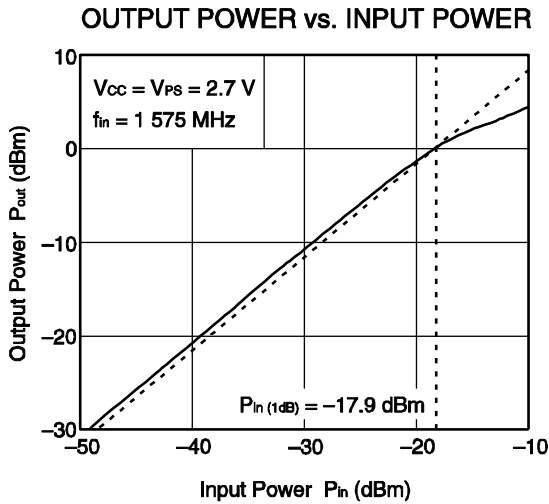
NOISE FIGURE vs. FREQUENCY



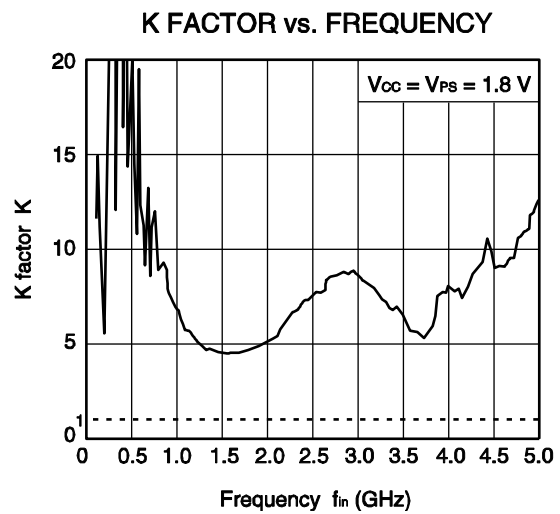
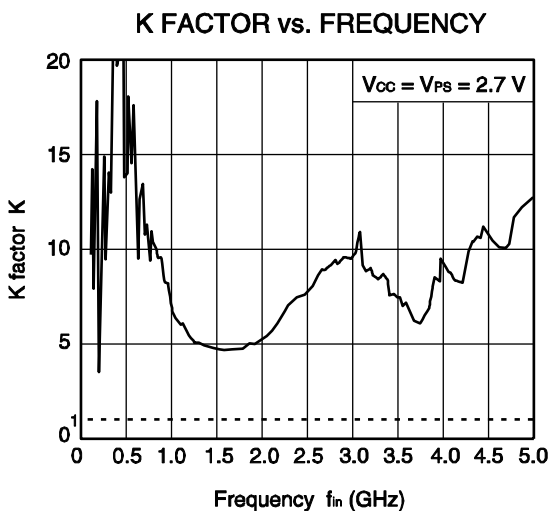
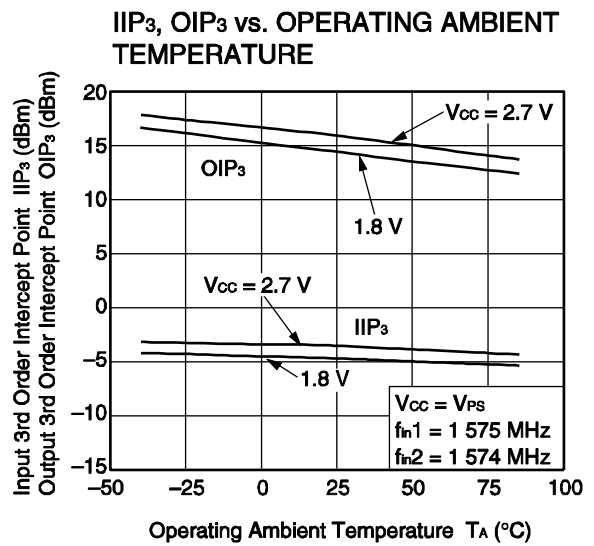
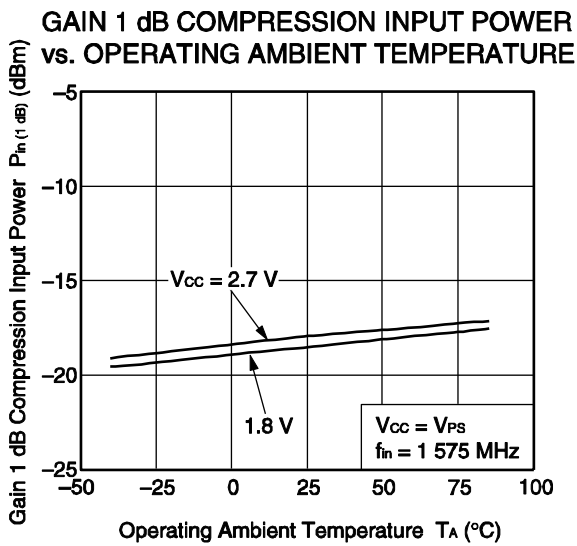
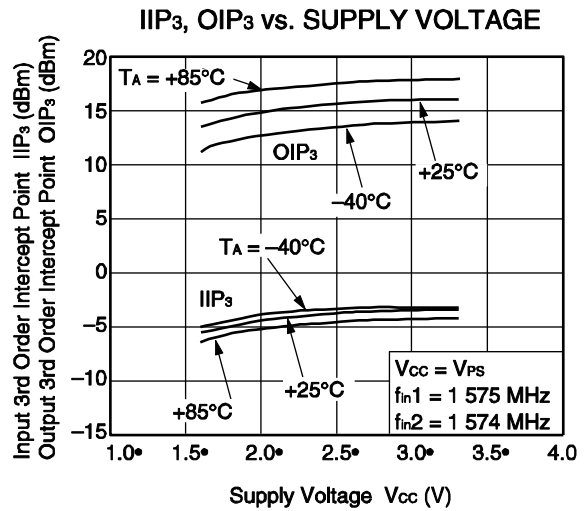
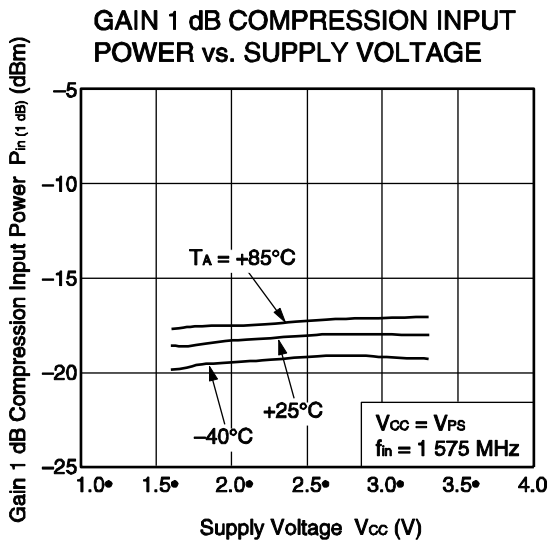
Remark The graphs indicate nominal characteristics.



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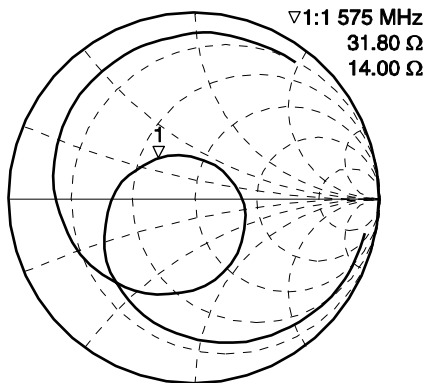
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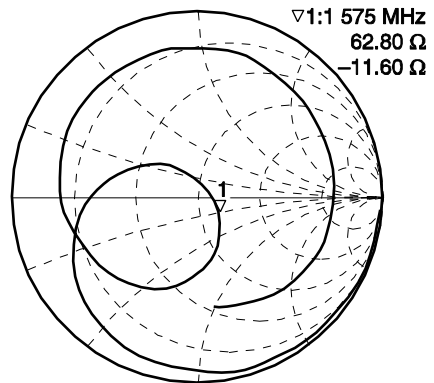
S-PARAMETERS ($T_A = +25^\circ\text{C}$, $V_{CC} = V_{PS} = 2.7\text{ V}$, monitored at connector on board)

S₁₁-FREQUENCY



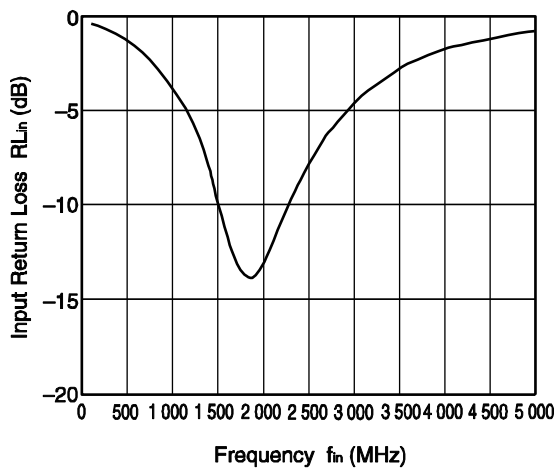
START 100.000 000 MHz STOP 5 000.000 000 MHz

S₂₂-FREQUENCY

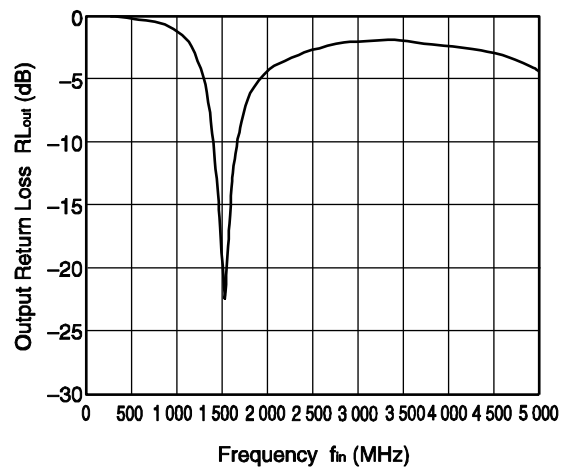


START 100.000 000 MHz STOP 5 000.000 000 MHz

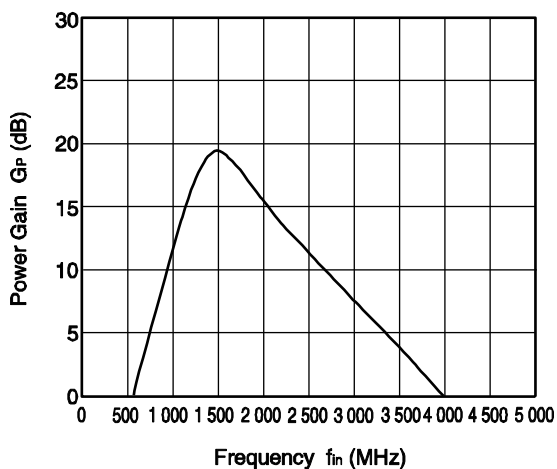
INPUT RETURN LOSS vs. FREQUENCY



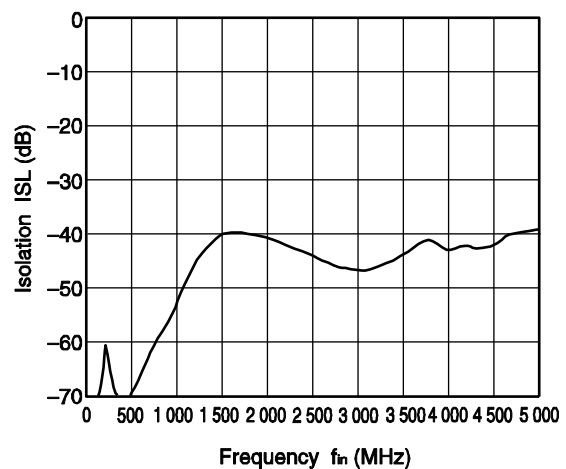
OUTPUT RETURN LOSS vs. FREQUENCY



POWER GAIN vs. FREQUENCY



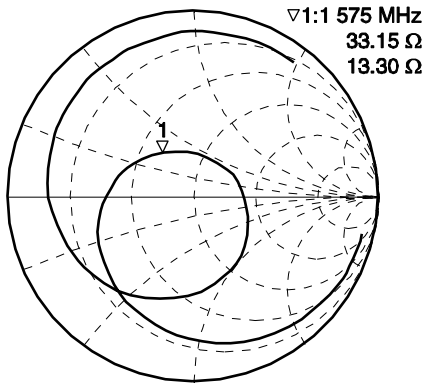
ISOLATION vs. FREQUENCY



Remark The graphs indicate nominal characteristics.

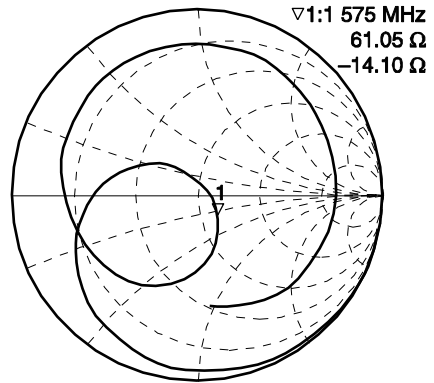
S-PARAMETERS ($T_A = +25^\circ\text{C}$, $V_{CC} = V_{PS} = 1.8\text{ V}$, monitored at connector on board)

S₁₁-FREQUENCY



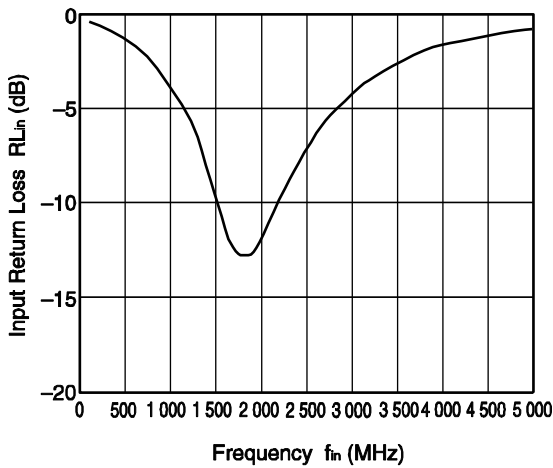
START 100.000 000 MHz STOP 5 000.000 000 MHz

S₂₂-FREQUENCY

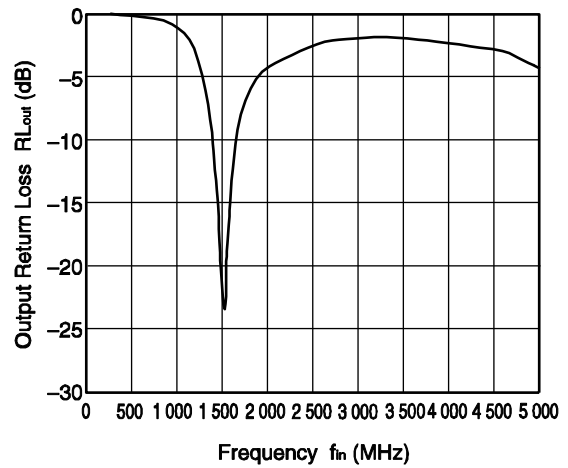


START 100.000 000 MHz STOP 5 000.000 000 MHz

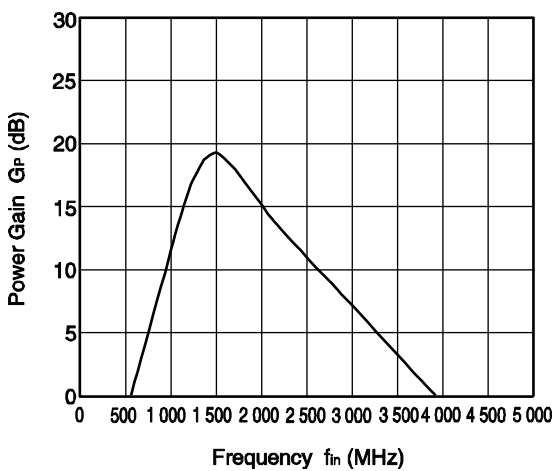
INPUT RETURN LOSS vs. FREQUENCY



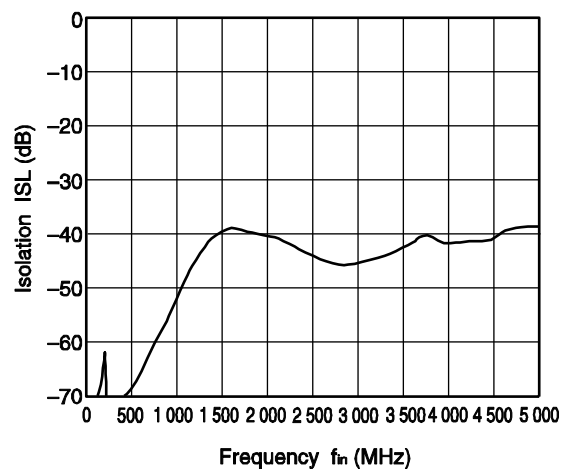
OUTPUT RETURN LOSS vs. FREQUENCY



POWER GAIN vs. FREQUENCY



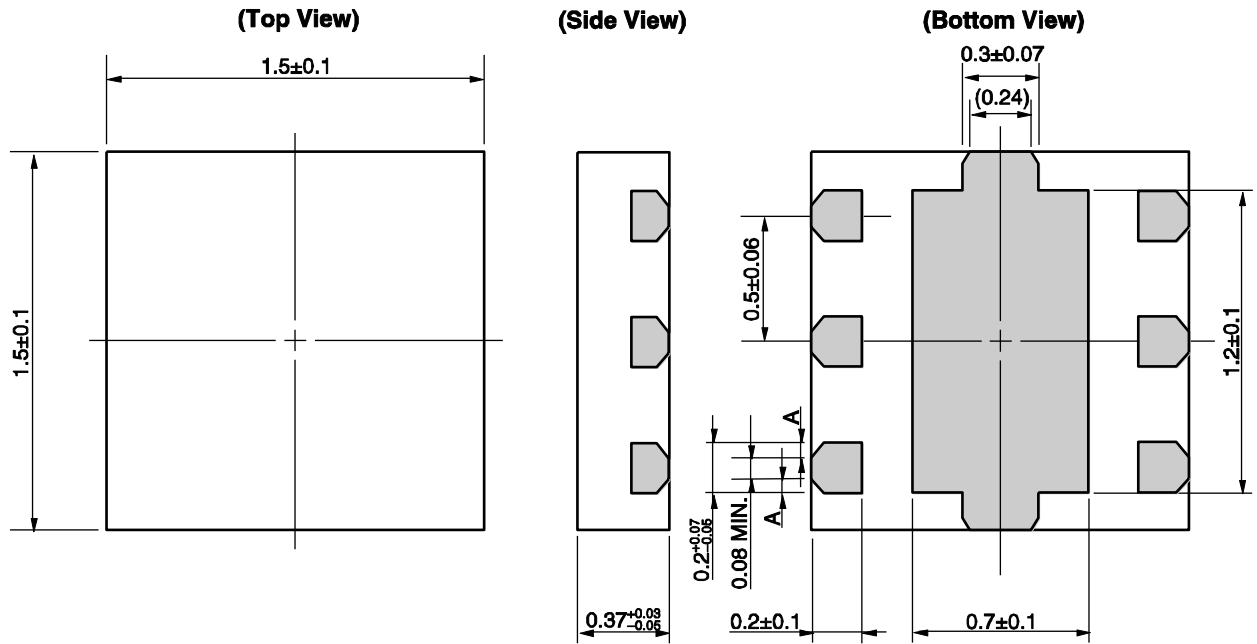
ISOLATION vs. FREQUENCY



Remark The graphs indicate nominal characteristics.

PACKAGE DIMENSIONS

6-PIN PLASTIC TSON (T6N) (UNIT: mm)



Remark A>0

() : Reference value

NOTES ON CORRECT USE

- (1) Observe precautions for handling because of electro-static sensitive devices.
- (2) Form a ground pattern as widely as possible to minimize ground impedance (to prevent undesired oscillation).
All the ground terminals must be connected together with wide ground pattern to decrease impedance difference.
- (3) The bypass capacitor should be attached to Vcc line.
- (4) Do not supply DC voltage to INPUT pin.

RECOMMENDED SOLDERING CONDITIONS

This product should be soldered and mounted under the following recommended conditions. For soldering methods and conditions other than those recommended below, contact your nearby sales office.

Soldering Method	Soldering Conditions	Condition Symbol
Infrared Reflow	Peak temperature (package surface temperature) : 260°C or below Time at peak temperature : 10 seconds or less Time at temperature of 220°C or higher : 60 seconds or less Preheating time at 120 to 180°C : 120±30 seconds Maximum number of reflow processes : 3 times Maximum chlorine content of rosin flux (% mass) : 0.2%(Wt.) or below	IR260
Wave Soldering	Peak temperature (molten solder temperature) : 260°C or below Time at peak temperature : 10 seconds or less Preheating temperature (package surface temperature) : 120°C or below Maximum number of flow processes : 1 time Maximum chlorine content of rosin flux (% mass) : 0.2%(Wt.) or below	WS260
Partial Heating	Peak temperature (terminal temperature) : 350°C or below Soldering time (per side of device) : 3 seconds or less Maximum chlorine content of rosin flux (% mass) : 0.2%(Wt.) or below	HS350

Caution Do not use different soldering methods together (except for partial heating).

Данный компонент на территории Российской Федерации

Вы можете приобрести в компании MosChip.

Для оперативного оформления запроса Вам необходимо перейти по данной ссылке:

<http://moschip.ru/get-element>

Вы можете разместить у нас заказ для любого Вашего проекта, будь то серийное производство или разработка единичного прибора.

В нашем ассортименте представлены ведущие мировые производители активных и пассивных электронных компонентов.

Нашей специализацией является поставка электронной компонентной базы двойного назначения, продукции таких производителей как XILINX, Intel (ex.ALTERA), Vicor, Microchip, Texas Instruments, Analog Devices, Mini-Circuits, Amphenol, Glenair.

Сотрудничество с глобальными дистрибьюторами электронных компонентов, предоставляет возможность заказывать и получать с международных складов практически любой перечень компонентов в оптимальные для Вас сроки.

На всех этапах разработки и производства наши партнеры могут получить квалифицированную поддержку опытных инженеров.

Система менеджмента качества компании отвечает требованиям в соответствии с ГОСТ Р ИСО 9001, ГОСТ РВ 0015-002 и ЭС РД 009

Офис по работе с юридическими лицами:

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